ESD Protection Diodes

Low Capacitance ESD Protection Diode for High Speed Data Lines

The ESD7321 ESD protection diodes are designed to protect high speed data lines from ESD. Low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines.

Features

- Low Capacitance (0.5 pF Max, I/O to GND)
- Protection for the Following IEC Standards: IEC 61000-4-2 (Level 4)
- Low ESD Clamping Voltage
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- USB 3.x
- MHL 2.0
- SATA/SAS
- PCI Express

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

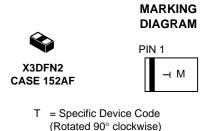
		,	
Rating	Symbol	Value	Unit
Operating Junction Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	ΤL	260	°C
IEC 61000-4-2 Contact (ESD) IEC 61000-4-2 Air (ESD)	ESD ESD	±15 ±15	kV kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com



M = Date Code

PIN CONFIGURATION AND SCHEMATIC



ORDERING INFORMATION

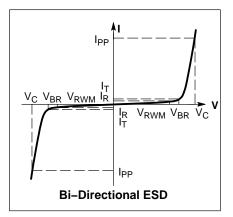
Device	Package	Shipping [†]
ESD7321MUT5G	X3DFN2 (Pb–Free)	10000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ IPP
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current



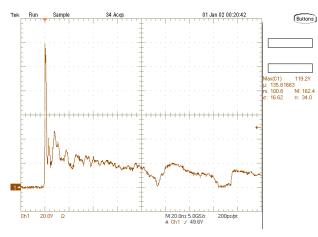
*See Application Note AND8308/D for detailed explanations of datasheet parameters.

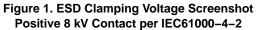
ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}				7.0	V
Breakdown Voltage	V _{BR}	I _T = 1 mA (Note 1)	8.0			V
Reverse Leakage Current	I _R	V _{RWM} = 7.0 V, I/O to GND			200	nA
Clamping Voltage	V _C	I _{PP} = 8 A - (IEC61000-4-2 Level 2 Equivalent (±4 kV Contact, ±8 kV Air))		18		V
ESD Clamping Voltage	V _C	Per IEC 61000-4-2	See Figures 1 and 2			
Junction Capacitance	CJ	V _R = 0 V, f = 1 MHz			0.5	pF
Dynamic Resistance	R _{DYN}	TLP Pulse		1		Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Breakdown voltage is tested from pin 1 to 2 and pin 2 to 1.





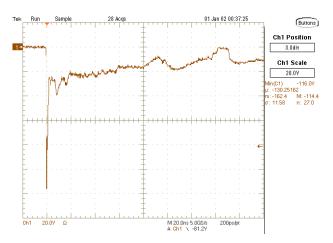


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000–4–2

ESD7321

TYPICAL CHARACTERISTICS

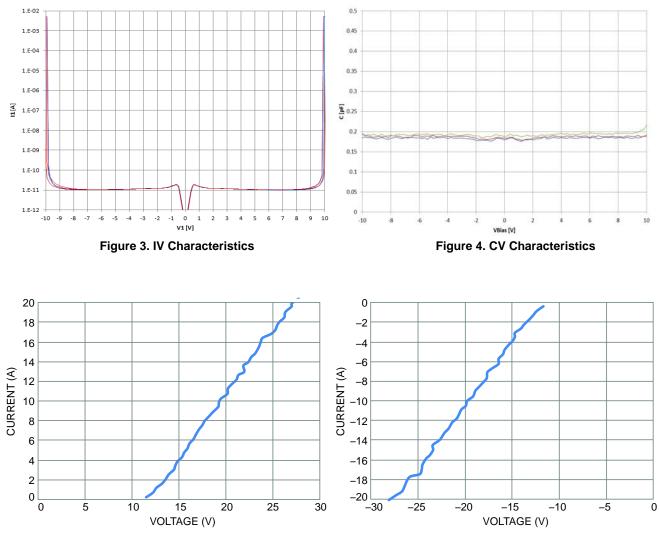


Figure 5. Positive TLP I–V Curve

Figure 6. Negative TLP I–V Curve

IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

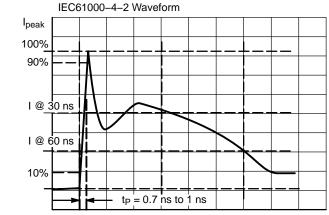


Figure 7. IEC61000-4-2 Spec

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 8. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 9 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.

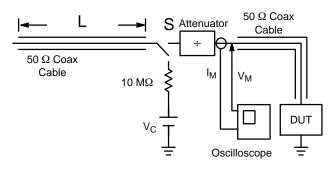


Figure 8. Simplified Schematic of a Typical TLP System

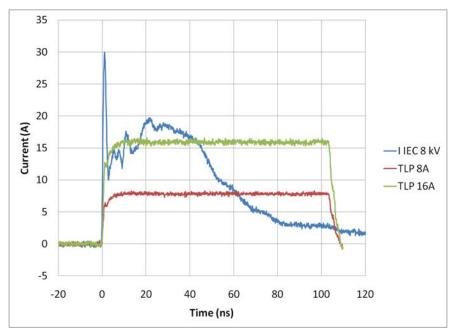


Figure 9. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

onsemi

	2x0.32x0.2 SE 152AF SSUE C	4, 0.35P			DAT	E 08 AUG	à 2023
	AS	ME Y14 NTROL	INING (4.5M, 1 LING I	994.			
				MIL	LIMETER	S	
PIN 1			DIM	MIN.	NDM.	MAX.	
(ΠΡΤΙΠΝΔΙ.)			А	0.25	0.29	0.33	
TOP VIEW			A1	0.00		0.05	4
— A1			A2	0.14	0.24	0.34	-
// 0.05 C			b	0.22	0.25	0.28	-
			b2	(0.150 RE	F	4
			D	0.58	0.62	0.66	-
			E	0.28	0.32	0.36	4
SIDE VIEW			e	(0.355 BS	C	4
SIDE VIEW .			L2	0.17	0.20	0.23	4
			L3	0.74—		F 2X 30	
		2Х	1	+[
= 2x l2 ⊕0.05@[C A B] B□TT□M VIEW	* F	or addit	JNTING	ormation	PRINT;	Ph-Free	2
Strateg the DN GENERIC Techniqu MARKING DIAGRAM*		trategy he ON S echnique	y and soldering details, please downloa Semiconductor Soldering and Mounting es Reference Manual, SOLDERRM/D.				wnload ting
PIN 1 XM							

X = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

 DOCUMENT NUMBER:
 98AON56472E
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 X3DFN2 0.62x0.32x0.24, 0.35P
 PAGE 1 OF 1

 onsemi and OOSEON. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>